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Vishay Semiconductors

Thyristor Surface Mount, Phase Control SCR, 8 A



PRIMARY CHARACTERISTICS						
I _{T(AV)}	8 A					
V _{DRM} /V _{RRM}	800 V					
V _{TM}	1.2 V					
I _{GT}	15 mA					
T _J	-40 to +125 °C					
Package	D ² PAK (TO-263AB)					
Circuit configuration	Single SCR					

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according JEDEC®-JESD 47





APPLICATIONS

- Input rectification and crow-bar (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-12TTS08S-M3 High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS									
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C, common heatsink of 1 °C/W	13.5	17	А						

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	8	^						
I _{T(RMS)}		12.5	A						
V _{RRM} /V _{DRM}		800	V						
I _{TSM}		110	A						
V _T	8 A, T _J = 25 °C	1.2	V						
dV/dt		150	V/µs						
dl/dt		100	A/µs						
TJ	Range	-40 to +125	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA						
VS-12TTS08S-M3	800	800	1.0						



ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average on-state current	I _{T(AV)}	T 100 °C 100° conduction helf sine ways	8					
Maximum RMS on-state current	I _{T(RMS)}	T _C = 108 °C, 180° conduction, half sine wave	12.5	Α				
Maximum peak one-cycle		10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C	95	A				
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied, T _J = 125 °C	110					
Marrian um 12t four frain a	I ² t	10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C	45	A ² s				
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied, T _J = 125 °C	64	A ² S				
Maximum l ² √t for fusing	I ² √t	$t = 0.1$ ms to 10 ms, no voltage reapplied, $T_J = 125$ °C	640	A²√s				
Maximum on-state voltage drop	V_{TM}	8 A, T _J = 25 °C	1.2	V				
On-state slope resistance	r _t	T 105 °C	16.2	mΩ				
Threshold voltage	V _{T(TO)}	T _J = 125 °C	0.87	V				
Marrian un variana and dive et la alcana august	1 /1	T _J = 25 °C	0.05					
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	$V_R = Rated V_{RRM}/V_{DRM}$	1.0					
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C	30	mA				
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C	50					
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80 \text{ %, } V_{DRM} = R_g - k = Open$	150	V/µs				
Maximum rate of rise of turned-on current	dI/dt		100	A/μs				

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P _{GM}		8.0	W			
Maximum average gate power	P _{G(AV)}		2.0	VV			
Maximum peak positive gate current	+ I _{GM}		1.5	Α			
Maximum peak negative gate voltage	- V _{GM}		10	V			
		Anode supply = 6 V, resistive load, T _J = - 65 °C	20				
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	15 m				
		Anode supply = 6 V, resistive load, T _J = 125 °C	10				
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2				
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V			
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V			
Maximum DC gate voltage not to trigger V		T = 105 °C V = Poted value	0.2				
Maximum DC gate current not to trigger I ₀		T _J = 125 °C, V _{DRM} = Rated value	0.1	mA			

SWITCHING								
PARAMETER SYMBOL TEST CONDITIONS VALUES UN								
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8					
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	3	μs				
Typical turn-off time	t _q	IJ = 123 G	100					



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +125	°C		
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.5			
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5			
Annewigant weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf ⋅ cm		
Mounting torque -	maximum			12 (10)	(lbf \cdot in)		
Marking device		Case style D ² PAK (TO-263AB) 12TTS			S08S		

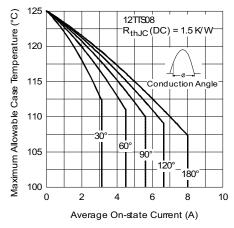


Fig. 1 - Current Rating Characteristics

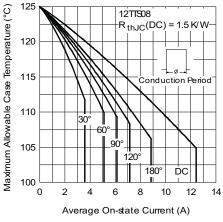


Fig. 2 - Current Rating Characteristics

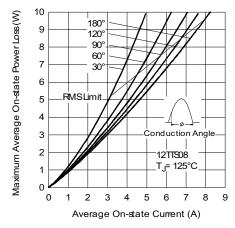


Fig. 3 - On-State Power Loss Characteristics

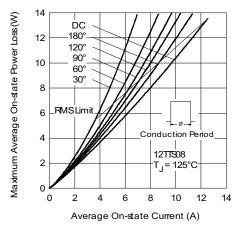


Fig. 4 - On-State Power Loss Characteristics

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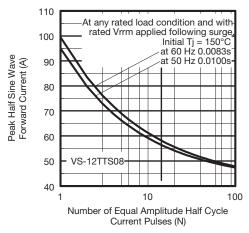


Fig. 5 - Maximum Non-Repetitive Surge Current

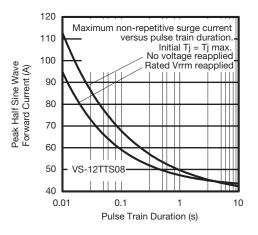


Fig. 6 - Maximum Non-Repetitive Surge Current

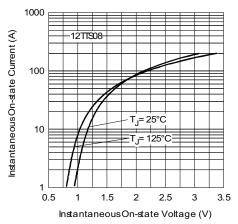
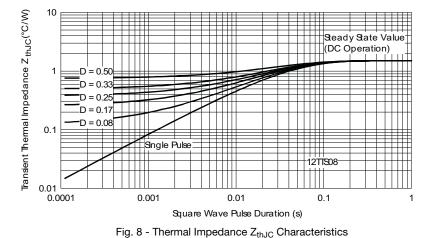


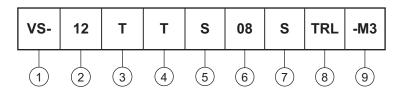
Fig. 7 - On-State Voltage Drop Characteristics





ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Current rating (12.5 A)
- 3 Circuit configuration:

T = single thyristor

4 - Package:

 $T = D^2PAK (TO-263AB)$

5 - Type of silicon:

S = standard recovery rectifier

- 6 Voltage rating (08 = 800 V)
- 7 S = surface mountable
- 8 • None = tube
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 9 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-12TTS08S-M3	50	1000	Antistatic plastic tubes					
VS-12TTS08STRR-M3	800	800	13" diameter reel					
VS-12TTS08STRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES		STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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